

830 nm Laser Diode, 200 mW



L830P200

Description

Thorlabs Ø5.6 mm, TO-can package, discrete laser diode is a compact light source suited to many applications. This diode is manufactured by OCLARO as Item # SM830-200-TO56-R01. This laser is fully compatible with our line of Laser Diode and TEC Controllers as well as our selection of Laser Diode Mounts and Collimation Solutions.

Specifications

Specification	Max
Storage Temperature	-40 to 85 °C
Operation Case Temperature	0 to 60 °C
Lead Soldering Temperature	260 °C

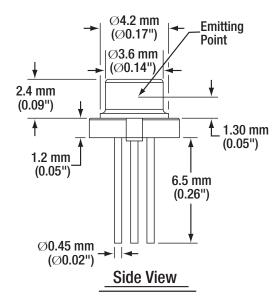


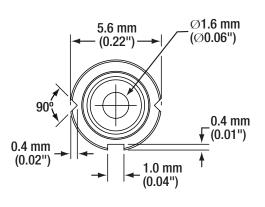
L830P200					
	Symbol	Min	Typical	Max	
Center Wavelength	λο	818 nm	824 nm	830 nm	
Output Power	Po	-	-	200 mW	
Operating Current CW @ Po	I _{op}	-	210 mA	230 mA	
Threshold Current	I _{TH}	-	40 mA	55 mA	
Operating Voltage @ Po	V_{op}	-	2.1 V	2.2 V	
Beam Divergence (FWHM) Parallel @ P _o	θ,,	5.5°	-	8.5°	
Beam Divergence (FWHM) Perpendicular @ P _o	$ heta_{\perp}$	16°	-	21°	
Slope Efficiency	ΔΡ/ΔΙ	-	1.0 W/A	-	

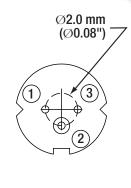
 $T_{CHIP} = 25^{\circ}C$



Drawings



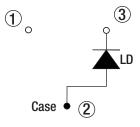




Top View

Rear View

Pin Code



Pin Code E

Pin	Description
1	-
2	Case Common
3	Laser Cathode

Us, Canada, & South America: +1-973-300-3000 | France: +33 (0) 970 444 844 | Europe: +49 (0) 8131-5956-0 | UK & Ireland: +86 (0)21-60561122

w.thorlabs.com

May 22, 2014 QTN007826-S01, Rev A